

## **Schottky Barrier Rectifier**

## INCHANGE SEMICONDUCTOR

# **MBRF40100CT**

### FEATURES

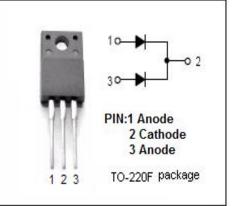
- With TO-220F packaging
- High Junction Temperature Capability
- Low forward voltage drop
- High current capability
- · Low power loss, high efficiency
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

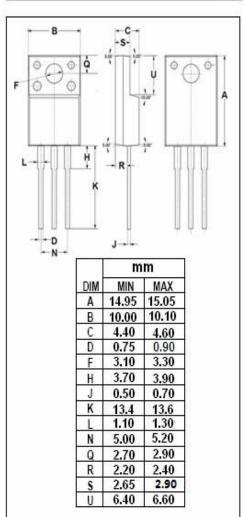
### **APPLICATIONS**

- Switching power supply
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL             | PARAMETER  | VALUE   | UNI<br>T |
|--------------------|--|---------|----------|
| Vrrm<br>Vrms<br>Vr | Peak Repetitive Reverse Voltage<br>RMS Voltage<br>DC Blocking Voltage                                      | 100     | V        |
| lf(AV)             | Average Rectified Forward Current@Tc=135°C   | 40      | А        |
| IFSM               | Nonrepetitive Peak Surge Current<br>(8.3ms single half sine-wave superimposed on<br>rated load conditions) | 280     | А        |
| TJ                 | Junction Temperature   | -55~150 | °C       |
| T <sub>stg</sub>   | Storage Temperature Range  | -55~150 | °C       |





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### <sup>1</sup> *isc & iscsemi* is registered trademark



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### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                            | MAX | UNIT |
|---------------------|--------------------------------------|-----|------|
| R <sub>th j-c</sub> | Thermal Resistance, Junction to Case | 3.5 | °C/W |

#### ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤1%)

| SYMBOL         | PARAMETER                             | CONDITIONS  | MAX                          | UNIT |
|----------------|---------------------------------------|---|------------------------------|------|
| VF             | Maximum Instantaneous Forward Voltage | IF= 10A ;Tc= 25℃<br>IF= 10A ;Tc= 125℃<br>IF= 20A ;Tc= 25℃<br>IF= 20A ;Tc= 125℃                            | 0.70<br>0.59<br>0.80<br>0.70 | V    |
| I <sub>R</sub> | Maximum Instantaneous Reverse Current | V <sub>R</sub> = rated V <sub>RRM</sub> ; Tj= 25°C<br>V <sub>R</sub> = rated V <sub>RRM</sub> ; Tj= 125°C | 1.0<br>20                    | mA   |

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